

Description

This -60V P-Channel MOSFET in a SOT-23-3 Plastic Package.

Applications

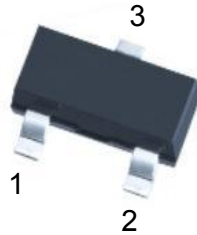
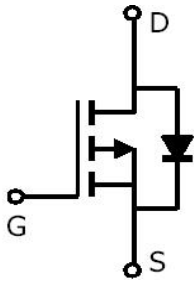
PWM application & Load switch

Features

- Ultra Low on-resistanceHF Product
- Fast switching
- Low on voltage
- Halogen-free Product

V_{DSS}	$R_{DS(on)}$	I_D
-60V	84mΩ	-5A

Equivalent Circuit & Pinning



PIN1 : Gate

PIN 2 : Source

PIN 3 : Drain

Absolute Maximum Ratings(Ta=25℃)

Parameter		Symbol	Rating	Unit
Drain–Source Voltage		V _{DSS}	-60	V
Gate–Body Leakage Voltage		V _{GSS}	±20	V
Drain Current - Continuous		I _D	-5	A
Power Dissipation (Surface Mounted on FR4 Board, t ≤ 10 sec.)		P _D	1.5	W
Operating and Storage Temperature Range		T _J , T _{STG}	-55~150	℃
Maximum Junction-to-Ambient	t ≤ 10s	R _{θJA}	118.6	℃/W
Maximum Junction-to-Ambient	Steady-State		161.6	℃/W
Maximum Junction-to-Lead	Steady-State	R _{θJL}	83.3	℃/W

Electrical Characteristics(Ta=25℃)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain–Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V$ $I_D=-250\mu A$	-60	-63		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1	-1.5	-2.5	V
Static Drain–Source On–Resistance	$R_{DS(on)}$	$V_{GS}=-10V$ $I_D=-2A$		84	100	mΩ
		$V_{GS}=-4.5V$ $I_D=-1A$		103	125	mΩ
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-60V$ $V_{GS}=0V$			-1.0	μA
Gate–Body Leakage.	I_{GSS}	$V_{GS}=-20V$			-100	nA
		$V_{GS}=20V$			100	nA
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=-1A$ $T_J=25^\circ C$			-1.2	V
Input Capacitance	C_{iss}	$V_{DS}=-25V$ $V_{GS}=0V$ $f=1.0MHz$		885		pF
Output Capacitance	C_{oss}			90		
Reverse Transfer Capacitance	C_{rss}			64		
Total Gate Charge	Q_g	$V_{DS}=-30V$ $V_{GS}=-10.0V$ $I_D=-5A$		25		nC
Gate-to-Source Charge	Q_{gs}			3		
Gate-to-Drain Charge	Q_{gd}			7		
Turn–On Delay Time	$t_{d(on)}$	$V_{DD}=-30V$ $V_{GS}=-10V$ $R_L=7.5\Omega$ $R_G=3\Omega$		8		ns
Turn–On Rise Time	t_r			4		
Turn–Off Delay Time	$t_{d(off)}$			32		
Turn–Off Fall Time	t_f			7		

Electrical Characteristic Curve

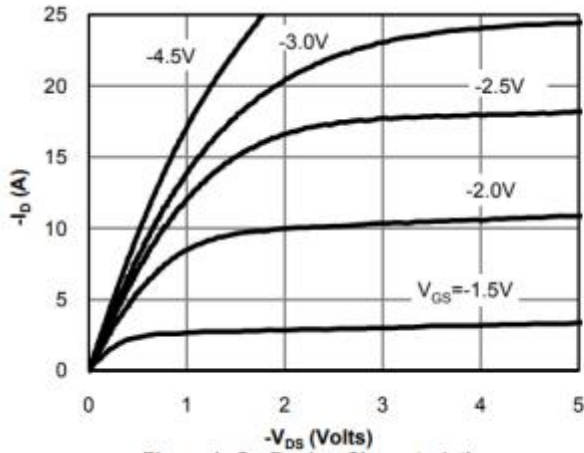


Figure 1: On-Region Characteristics

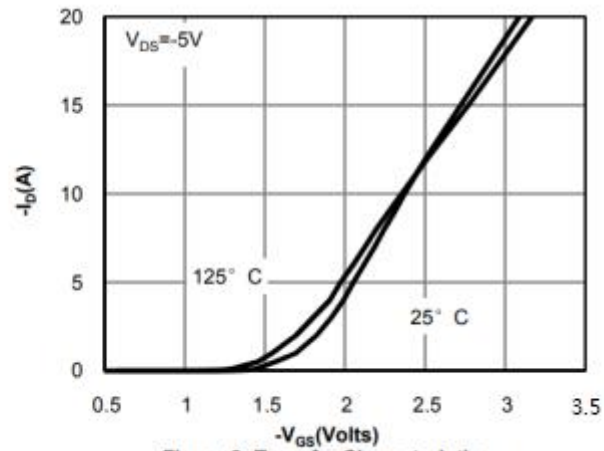


Figure 2: Transfer Characteristics

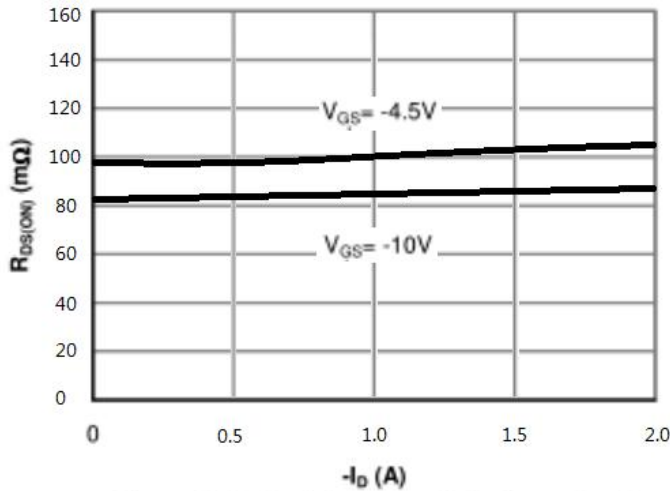


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

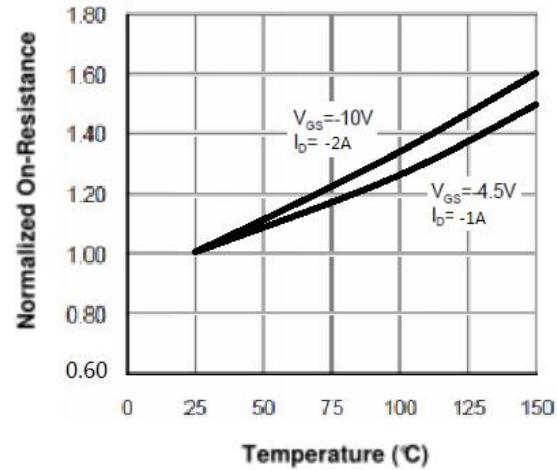


Figure 4: On-Resistance vs. Junction Temperature

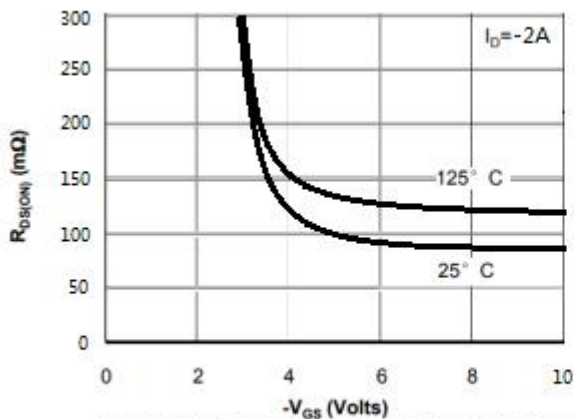


Figure 5: On-Resistance vs. Gate-Source Voltage

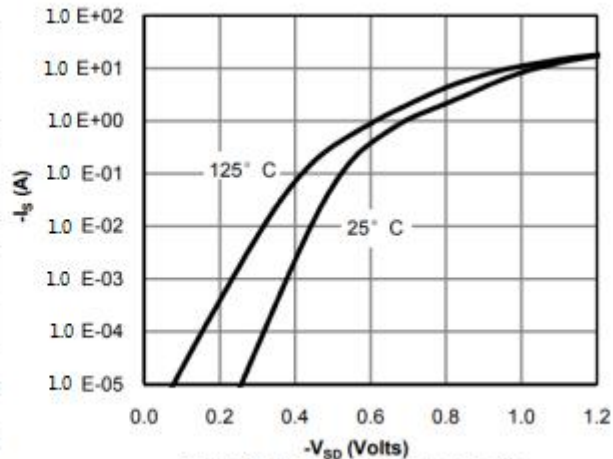


Figure 6: Body-Diode Characteristics

Electrical Characteristic Curve

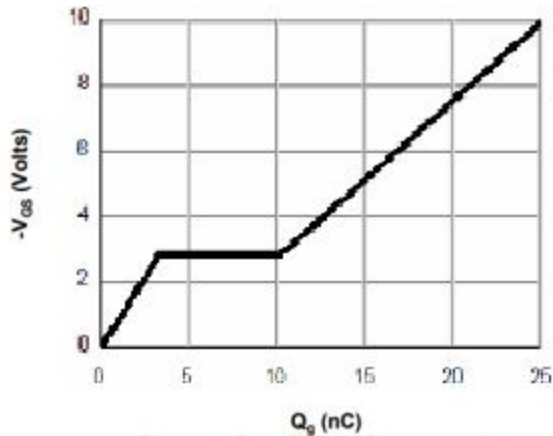


Figure 7: Gate-Charge Characteristics

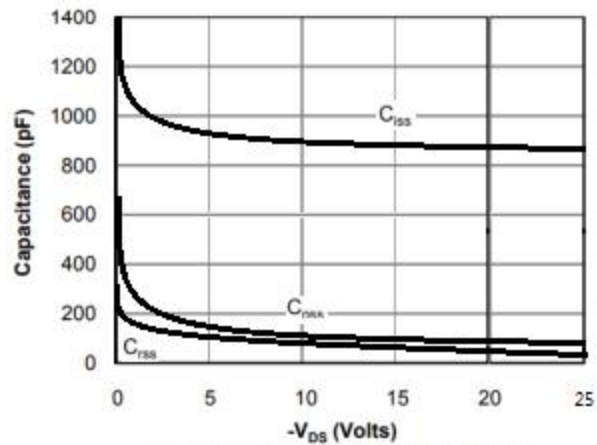


Figure 8: Capacitance Characteristics

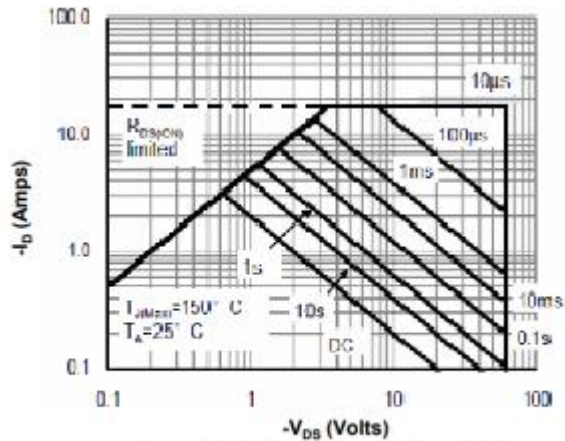


Figure 9: Maximum Forward Biased Safe Operating Area

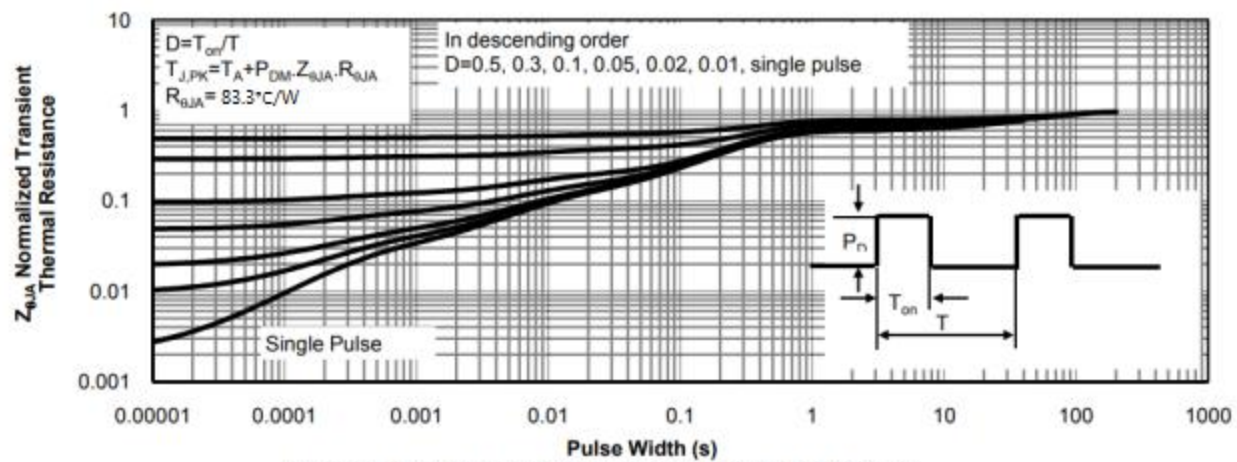
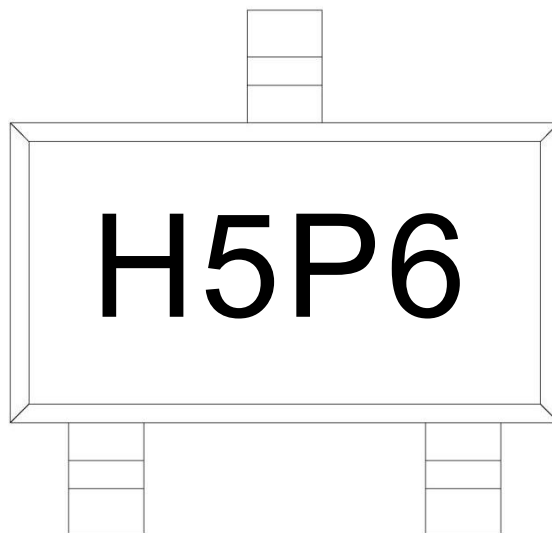


Figure 10: Normalized Maximum Transient Thermal Impedance

Marking Instructions



Note:

H : Company Code.

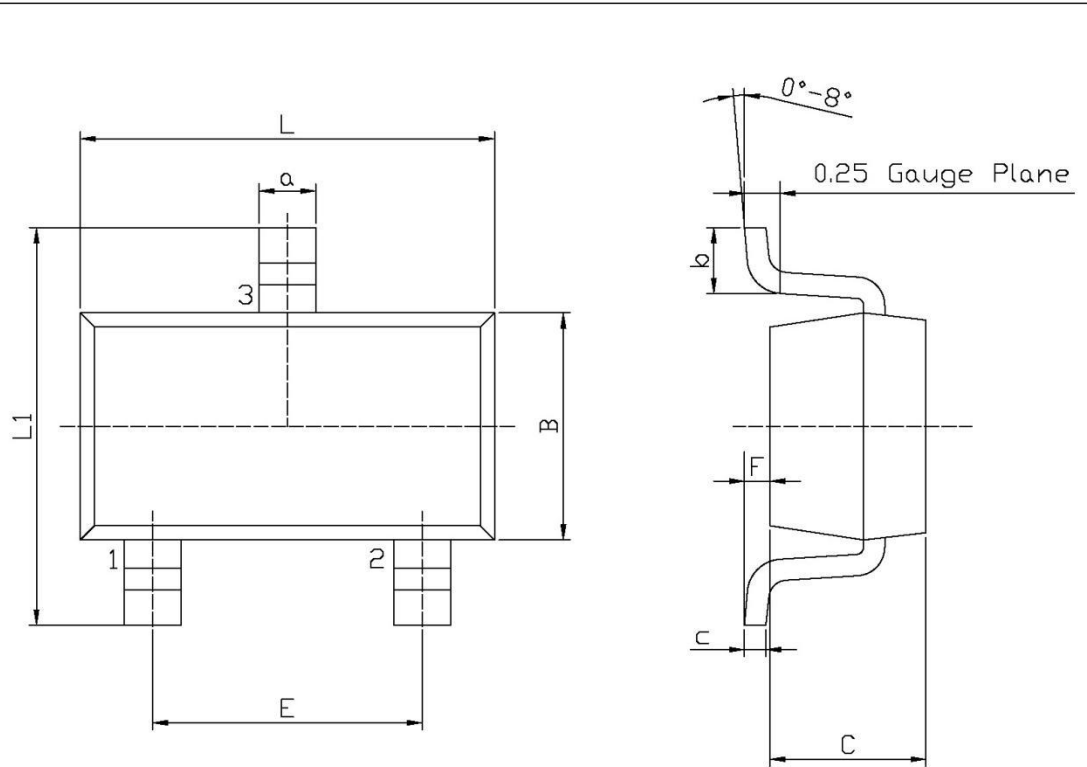
5P6: Product Type

Packaging SPEC.

REEL INFORMATION

Package Type	Units					Dimension (unit: mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT23-3	3,000	10	30,000	4	120,000	7" x8	210×205×205	445×230×435

Package Outline Dimensions



Unit: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.82	3.02	a	0.35	0.50
B	1.50	1.70	c	0.10	0.20
C	0.90	1.30	b	0.35	0.55
L1	2.60	3.00	F	0	0.15
E	1.80	2.00			

SOT23-3